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LMV431/LMV431A/LMV431B Low-Voltage (1.24V) Adjustable Precision Shunt Regulators

General Description

The LMV431, LMV431A and LMV431B are precision 1.24V shunt regulators capable of adjustment to 30V. Negative feedback from the cathode to the adjust pin controls the cathode voltage, much like a non-inverting op amp configuration (Refer to Symbol and Functional diagrams). A two resistor voltage divider terminated at the adjust pin controls the gain of a 1.24V band-gap reference. Shorting the cathode to the adjust pin (voltage follower) provides a cathode voltage of a 1.24V.

The LMV431, LMV431A and LMV431B have respective initial tolerances of 1.5%, 1% and 0.5%. The LMV431 and LMV431A are available in commercial and Industrial temperature ranges. The LMV431B is only available in commercial temperature range.

The LMV431, LMV431A and LMV431B functionally lends themselves to several applications that require zener diode type performance at low voltages. Applications include a 3V to 2.7V low drop-out regulator, an error amplifier in a 3V off-line switching regulator and even as a voltage detector. These parts are typically stable with capacitive loads greater than 10nF and less than 50pF.

The LMV431, LMV431A and LMV431B provide performance at a competitive price.

Connection Diagrams



Top View



- Low Voltage Operation/Wide Adjust Range (1.24V/30V)
- 0.5% Initial Tolerance (LMV431B)
- Temperature Compensated for Industrial Temperature Range (39 PPM/°C for the LMV431AI)
- Low Operation Current (55µA)
- Low Output Impedance (0.25Ω)
- Fast Turn-On Response
- Low Cost

Applications

- Shunt Regulator
- Series Regulator
- Current Source or Sink
- Voltage Monitor
- Error Amplifier
- 3V Off-Line Switching Regulator
- Low Dropout N-Channel Series Regulator



*Pin 1 is not internally connected.

*Pin 2 is internally connected to Anode pin. Pin 2 should be either floating or connected to Anode pin.

Top View

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N09A

N09A

N09B

N09B

1%

1%

1.5%

1.5%

LMV431ACM5

LMV431ACM5X

LMV431CM5

LMV431CM5X

DC/AC Test Circuits for Table and Curves











FIGURE 3. Test Circuit for Off-State Current

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Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Storage Temperature Range	–65°C to +150°C
Operating Temperature Range	
Industrial (LMV431AI, LMV431I)	-40°C to +85°C

LMV4311 Electrical Characteristics

 $T_A = 25^{\circ}C$ unless otherwise specified

Symbol	Parameter	Conditions		Min	Тур	Max	Units
V_{REF}	Reference Voltage	$V_Z = V_{REF}, I_Z = 10mA$	$T_A = 25^{\circ}C$	1.222	1.24	1.258	1
		(See Figure 1)	T _A = Full Range	1.202		1.278	
V _{DEV}	Deviation of Reference Input Voltage	$V_Z = V_{REF}, I_Z = 10 \text{mA},$			6	20	mV
	Over Temperature (Note 4)	T _A = Full Range (See Fig					
ΔV_{REF}	Ratio of the Change in Reference	I _z = 10mA <i>(see Figure 2)</i>			-1.5	-2.7	mV/V
ΔV_7	Voltage to the Change in Cathode	V _Z from V _{REF} to 6V					
	Voltage	$R_1 = 10k, R_2 = \infty$ and 2.6K					
I _{REF}	Reference Input Current	R ₁ = 10k					

LMV431AI Electrical Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Units
V _{REF}	Reference Voltage	$V_Z = V_{REF}, I_Z = 10mA$	$T_A = 25^{\circ}C$	1.228	1.24	1.252	
		(See Figure 1)	T _A = Full Range	1.215		1.265	V
V _{DEV}	Deviation of Reference Input Voltage	$V_Z = V_{REF}, I_Z = 10 \text{mA},$			6	20	mV
	Over Temperature (Note 4)	T _A = Full Range (See Fig					
ΔV_{BFF}	Ratio of the Change in Reference	I _z = 10mA (see Figure 2)			-1.5	-2.7	mV/V
ΔV_7	Voltage to the Change in Cathode	V _Z from V _{REF} to 6V					
	Voltage	$R_1 = 10k, R_2 = \infty$ and 2.6K					
I _{REF}	Reference Input Current	$R_1 = 10k\Omega, R_2 = \infty$			0.15	0.5	μA
		I _I = 10mA <i>(see Figure 2)</i>					
∝I _{REF} Deviation of Reference Input Current R ₁ = 10kΩ, R ₂ = ∞,			0.1	0.4			
	over Temperature $I_I = 10$ mA, $T_A =$ Full Range (see Figure 2)			0.1	0.4	μΑ	
I _{Z(MIN)}	Minimum Cathode Current for	V _Z = V _{REF} (see Figure 1)			55	00	
Regulation				55	80	μΑ	
I _{Z(OFF)}	Off-State Current	$V_Z = 6V, V_{REF} = 0V$ (see Figure 3)			0.001	0.1	μA
r _z	Dynamic Output Impedance (Note 5)	$V_Z = V_{REF}$, $I_Z = 0.1$ mA to 15mA					
		Frequency = 0Hz (see Figure 1)			0.25	0.4	Ω

 $T_A = 25^{\circ}C$ unless otherwise specified

LMV431BC Electrical Characteristics

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Symbol	Parameter	Condition	Min	Тур	Max	Units	
V _{REF}	Reference Voltage	$V_Z = V_{REF}, I_Z = 10mA$	T _A = 25°C	1.234	1.24	1.246	
		(See Figure 1)	T _A = Full Range	1.227		1.253	v
V _{DEV}	Deviation of Reference Input Voltage	$V_Z = V_{REF}, I_Z = 10 \text{mA},$			4	12	mV
	Over Temperature (Note 4)	T _A = Full Range (See Fig					
ΔV_{BFF}	Ratio of the Change in Reference	I _z = 10mA <i>(see Figure 2)</i>			-1.5	-2.7	mV/V
ΔV_{7}	Voltage to the Change in Cathode	V _Z from V _{REF} to 6V					
2	Voltage	$R_1 = 10k, R_2 = \infty$ and 2.6					
I _{REF}	Reference Input Current	$R_1 = 10k\Omega, R_2 = \infty$ I ₁ = 10mA (see Figure 2)			0.15	0.50	μA
∝I _{REF}	Deviation of Reference Input Current	$R_1 = 10k\Omega, R_2 = \infty,$			0.05	0.0	
	over Temperature	$I_1 = 10mA, T_A = Full Range (see Figure 2)$			0.05	0.3	μΑ
$I_{Z(MIN)}$ Minimum Cathode Current for $V_Z = V_{RE}$		V _Z = V _{REF} (see Figure 1))		55	80	μA
	Regulation				55		
I _{Z(OFF)}	Off-State Current	$V_Z = 6V, V_{REF} = 0V$ (see Figure 3)			0.001	0.1	μA
r _z	Dynamic Output Impedance (Note 5)	$V_Z = V_{REF}$, $I_Z = 0.1$ mA to 15mA Frequency = 0Hz <i>(see Figure 1)</i>					
					0.25	0.4	Ω

 $T_A = 25^{\circ}C$ unless otherwise specified

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Electrical specifications do not apply when operating the device beyond its rated operating conditions.

Note 2:

LMV431BC Electrical Characteristics (Continued)



The average temperature coefficient of the reference input voltage, ${\scriptstyle \propto}V_{REF},$ is defined as:

$$\propto V_{\mathsf{REF}} \frac{\mathsf{ppm}}{^{\circ}\mathsf{C}} = \frac{\pm \left[\frac{V_{\mathsf{Max}} - V_{\mathsf{Min}}}{V_{\mathsf{REF}} (\mathsf{at} \, 25^{\circ}\mathsf{C})}\right] 10^{6}}{\mathsf{T}_{2} - \mathsf{T}_{1}} = \frac{\pm \left[\frac{V_{\mathsf{DEV}}}{V_{\mathsf{REF}} (\mathsf{at} \, 25^{\circ}\mathsf{C})}\right] 10^{6}}{\mathsf{T}_{2} - \mathsf{T}_{1}}$$

Where:

 $T_2 - T_1$ = full temperature change.

[∞]V_{REF} can be positive or negative depending on whether the slope is positive or negative. Example: V_{DEV} = 6.0mV, _{REF} = 1240mV, T₂ − T₁ = 125°C.

$$\propto V_{\mathsf{REF}} = \frac{\left[\frac{6.0 \text{ mV}}{1240 \text{ mV}}\right] 10^{6}}{125^{\circ}\text{C}} = +39 \text{ ppm/}^{\circ}\text{C}$$

Note 5: The dynamic output impedance, r_Z , is defined as:

$$r_{Z} = \frac{\Delta V_{Z}}{\Delta I_{Z}}$$

When the device is programmed with two external resistors, R1 and R2, (see Figure 2), the dynamic output impedance of the overall circuit, r_z, is defined as:

$$r_{Z} = \frac{\Delta V_{Z}}{\Delta I_{Z}} \cong \left[r_{Z} \left(1 + \frac{R1}{R2} \right) \right]$$

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Typical Performance Characteristics Reference Voltage vs. Junction Temperature Reference Input Current vs. Junction Temperature 1.248 190 1.246 180 170 S 1.244 Reference Current (nA) Reference Voltage 160 1.242 150 1.24 140 1.238 130 1.236 120 1.234 110 1.232 100 25 100 125 150 -50 -25 0 50 75 -50 Junction Temperature (°C) DS100958-50 Cathode Current vs. Cathode Voltage 1 15.0 250 Cathode Current (mA) Cathode Current 2.00 mA 50µ/ /div div -15.0 E -250 (0) 200 m/div 1.5 - 1 200 m/ arv Cathode Voltage (V) DS100958-51 Off-State Cathode Current vs. Junction Temperature 40 Delta Reference Voltage per Delta Cathode Voltage (mV/V)Off-State Cathode Current (nA) 35 30 0 25 -0.5 20 -1 15 10 -1.5 5 -2 0 75 100 -50 -25 0 25 50 125 -2.5 Junction Temperature (°C) DS100958-63 -3 -50

-25 0 25 50 75 100 Junction Temperature (°C) DS100958-62

Cathode Current vs. Cathode Voltage 2







Typical Performance Characteristics (Continued)





Noise vs Frequency







Typical Performance Characteristics (Continued) **Reference Impedance vs Frequency** 100 Reference Impedance (Ω) 10 0.1 0.01 1k 10k 100k 10M 1M Frequency (Hz) DS100958-56 Pulse Response 1 3.5 3 Input and Output Voltage (V) Input 2.5 $R_{S} = 18k$ 2 1.5 Output 1 0.5 0 0 1 2 3 4 5 6 7 8

Time (µs) DS100958-57







100Ω

Test Circuit for Pulse Response 2



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Notes

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